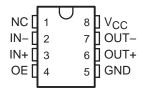
SLCS002D - JUNE 1983 - REVISED AUGUST 2003

- Operates From a Single 5-V Supply
- 0-V to 5.5-V Common-Mode Input Voltage Range
- Self-Biased Inputs
- Complementary 3-State Outputs
- Enable Capability
- Hysteresis . . . 5 mV Typ
- Response Times . . . 25 ns Typ

## D, P, PS, OR PW PACKAGE (TOP VIEW)



NC-No internal connection

#### description/ordering information

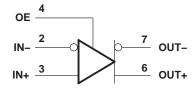
The TL712 is a high-speed comparator fabricated with bipolar Schottky process technology. The circuit has differential analog inputs and complementary 3-state TTL-compatible logic outputs with symmetrical switching characteristics. When the output enable (OE) is low, both outputs are in the high-impedance state. This device operates from a single 5-V supply and is useful as a disk memory read-chain data comparator.

#### ORDERING INFORMATION

TA	PACKAC	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP (P)	Tube of 50	TL712CP	TL712CP
	COIC (D)	Tube of 75	TL712CD	TI 7400
000 to 7000	SOIC (D)	Reel of 2500	TL712CDR	TL712C
0°C to 70°C	SOP (PS)	Reel of 2000	TL712CPSR	T712
	TOCOD (DIA))	Tube of 150	TL712CPW	T740
	TSSOP (PW)	Reel of 2000	TL712CPWR	T712

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### symbol (positive logic)

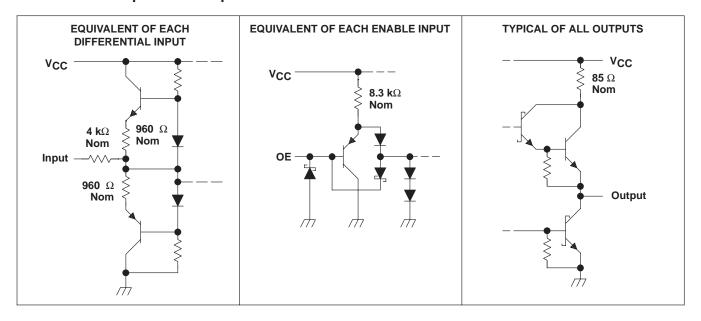




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#### schematics of inputs and outputs



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)		$. \dots \dots \pm 25 \ V \\ \dots \dots \pm 25 \ V$
Output enable voltage		
Low-level output current, I <sub>OL</sub>		50 MA
Package thermal impedance, $\theta_{JA}$ (see Notes 3 and 4)	): D package	97°C/W
•	P package	85°C/W
	PS package	95°C/W
	PW package	
Operating virtual junction temperature, T.I	. •	
Lead temperature 1,6 mm (1/16 inch) from case for 10		
Storage temperature range, T <sub>stg</sub>		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the "recommended operating conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground.
  - 2. Differential voltage values are at IN+ with respect to IN -.
  - 3. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
  - 4. The package thermal impedance is calculated in accordance with JESD 51-7.



#### recommended operating conditions

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.75	5	5.25	V
VIC	Common-mode input voltage	0		5.5	V
ІОН	High-level output current			-1	mA
lOL	Low-level output current			16	mA
TA	Operating free-air temperature	0		70	°C

## electrical characteristics at $V_{CC}$ = 5 V, $T_A$ = 25 $^{\circ}C$

	PARAMETER	TEST CON	DITIONS	MIN	TYP	MAX	UNIT
VT	Threshold voltage (V <sub>T+</sub> and V <sub>T-</sub> )	V <sub>ICR</sub> = 0 to 5 V		-100†		100	mV
V <sub>hys</sub>	Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> )				5		mV
Vон	High-level output voltage	$V_{ID} = 100 \text{ mV},$	$I_{OH} = -1 \text{ mA}$	2.7	3.5		V
VOL	Low-level output voltage	$V_{ID} = -100 \text{ mV},$	$I_{OL} = 16 \text{ mA}$		0.4	0.5	V
loz	Off-state output current	V <sub>O</sub> = 2.4 V				-20	μΑ
Ц	Enable current	V <sub>I</sub> = 5.5 V				100	μΑ
lН	High-level enable current	V <sub>IH</sub> = 2.7 V				20	μΑ
Iμ	Low-level enable current	V <sub>IL</sub> = 0.4 V				-360	μΑ
rį	Differential input resistance			4			kΩ
r <sub>O</sub>	Output resistance					100	Ω
los	Short-circuit output current			-15		-85	mA
ICC	Supply current	$V_{ID} = 0$ ,	No load		17	20	mA

<sup>&</sup>lt;sup>†</sup> The algebraic convention, where the more-negative limit is designated as minimum, is used in this data sheet for input threshold voltage levels only.

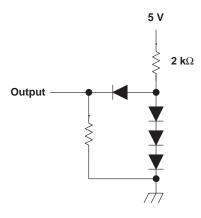
## switching characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

	PARAMETER	TE	TYP	UNIT	
tPLH	Propagation delay time, low-to-high-level output	TTL load.	See Note 5 and Figure 1	25	ns
tPHL	Propagation delay time, high-to-low-level output	i i L loau,	See Note 5 and Figure 1	25	ns

NOTE 5: The response time specified is for a 100-mV input step with 5-mV overdrive (105 mV total) and is the interval between the input step function and the instant when the output crosses 2.5 V.



#### PARAMETER MEASUREMENT INFORMATION



NOTE A: All diodes are 1N4148 or equivalent.

Figure 1. TTL Output Load Circuit

#### TYPICAL CHARACTERISTICS

# OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVE VOLTAGES

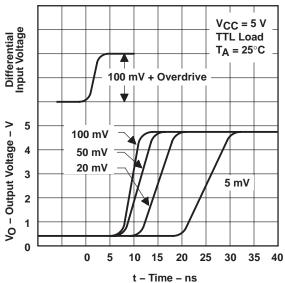


Figure 2

# OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVE VOLTAGES

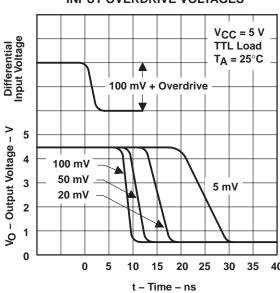


Figure 3

#### **TYPICAL CHARACTERISTICS**

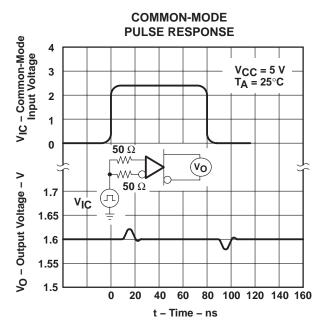


Figure 4





25-Sep-2019

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL712CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL712C	Samples
TL712CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL712C	Samples
TL712CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL712C	Samples
TL712CP	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL712CP	Samples
TL712CPSR	ACTIVE	so	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T712	Samples
TL712CPSRG4	ACTIVE	so	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T712	Samples
TL712CPWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T712	Samples
TL712CPWRE4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T712	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



#### PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL712CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL712CPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
TL712CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL712CPWR	TSSOP	PW	8	2000	367.0	367.0	35.0



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### PS (R-PDSO-G8)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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